

## 20V/4.7A N-Channel MOSFET

**Features**

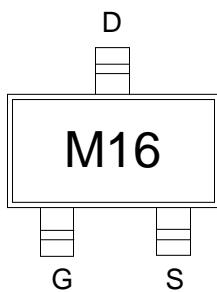
- Trench Power LV MOSFET technology
- High Power and current handing capability

**Product Summary**

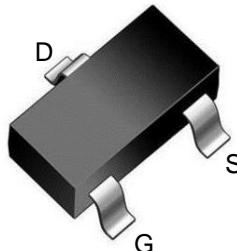
$V_{DS}$	$R_{DS(ON)} \text{ MAX}$	$I_D \text{ MAX}$
20V	47mΩ@4.5V	4.7A
	65mΩ@2.5V	

**Application**

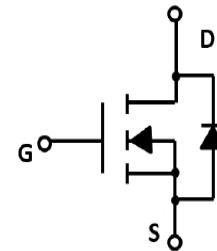
- PWM application
- Load switch



M16: Device code



SOT-23 top view



Schematic diagram

Marking and pin assignment

**Absolute Maximum Ratings (TA=25°C unless otherwise noted)**

Symbol	Parameter	Rating	Unit
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**Common Ratings (TC=25°C Unless Otherwise Noted)**

$V_{DS}$	Drain-Source Breakdown Voltage	20	V	
$V_{GS}$	Gate-Source Voltage	±10	V	
$T_J$	Maximum Junction Temperature	150	°C	
$T_{STG}$	Storage Temperature Range	-50 to 155	°C	
$I_S$	Diode Continuous Forward Current	Tc=25°C	4.7	A

**Mounted on Large Heat Sink**

$I_{DM}$	Pulse Drain Current Tested	Tc=25°C	10	A
$I_D$	Continuous Drain Current@GS=10V	Tc=25°C	4.7	A
$P_D$	Maximum Power Dissipation	Tc=25°C	0.7	W
$R_{QJA}$	Thermal Resistance Junction-to-Ambient @ Steady State		178	°C/W

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, ID=250μA	20	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , ID=250μA	0.45	0.7	0.9	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =4.5V, ID=3.6A	--	37	47	mΩ
		V <sub>GS</sub> =2.5V, ID=3.1A	--	53	65	
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz	--	220	--	pF
C <sub>OSS</sub>	Output Capacitance		--	35	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	25	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =10V, ID=3.2A, V <sub>GS</sub> =4.5V	--	3.6	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	0.9	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	0.8	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	VDD=10V, ID=1.5A, VGS=4.5V, RG=3Ω	--	7	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	57	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	15	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	53	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>s</sub> =3.2A,	--	--	1.2	V

## Typical Operating Characteristics

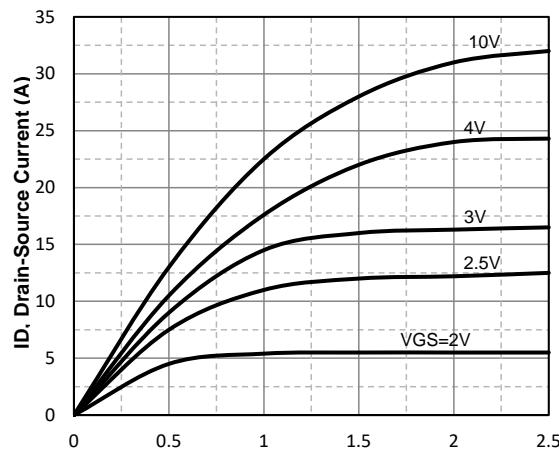


Fig1. Typical Output Characteristics

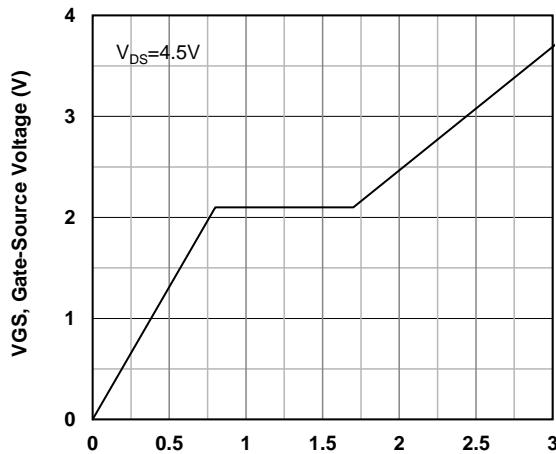


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

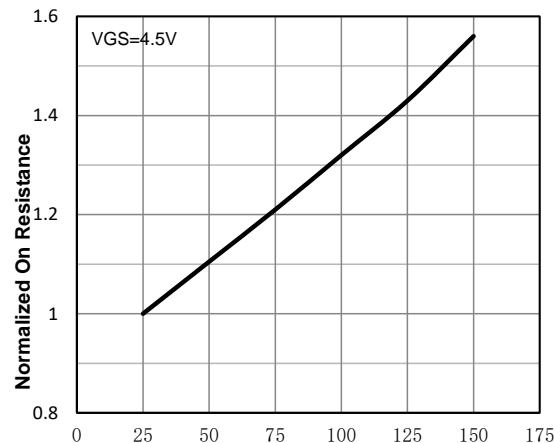


Fig3. Normalized On-Resistance Vs. Temperature

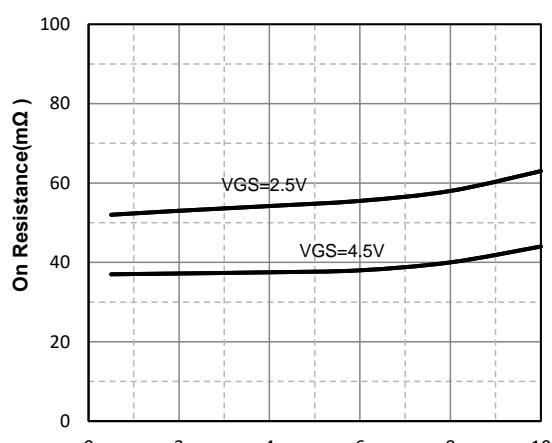


Fig4. On-Resistance Vs. Drain-Source Current

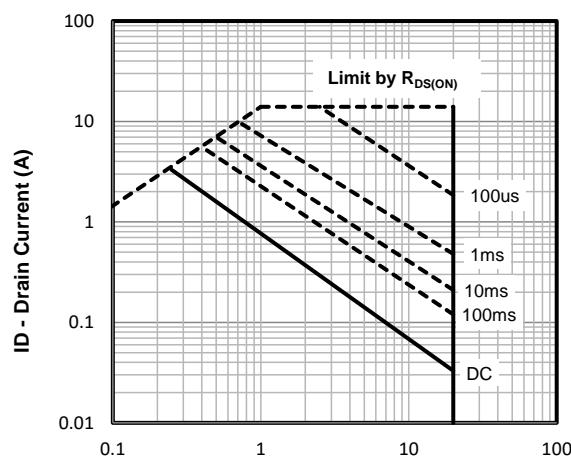


Fig5. Maximum Safe Operating Area

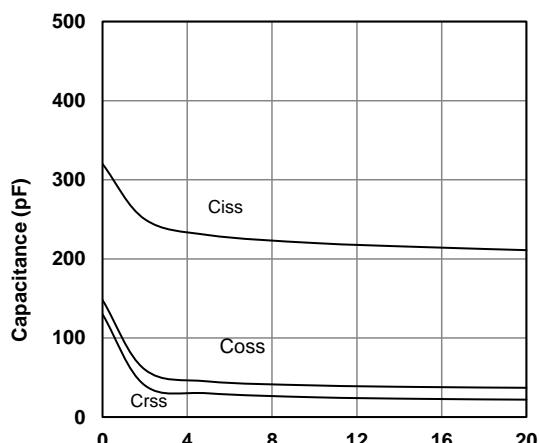
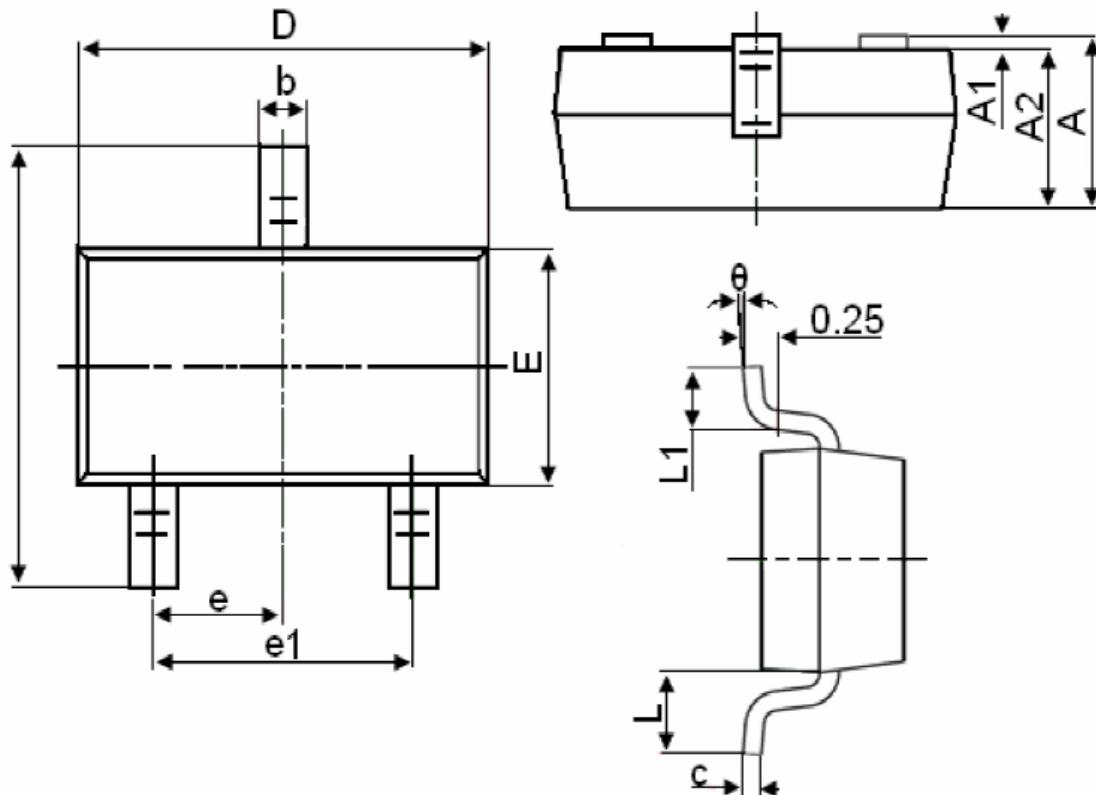


Fig6 Typical Capacitance Vs.Drain-Source Voltage

## SOT-23 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

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